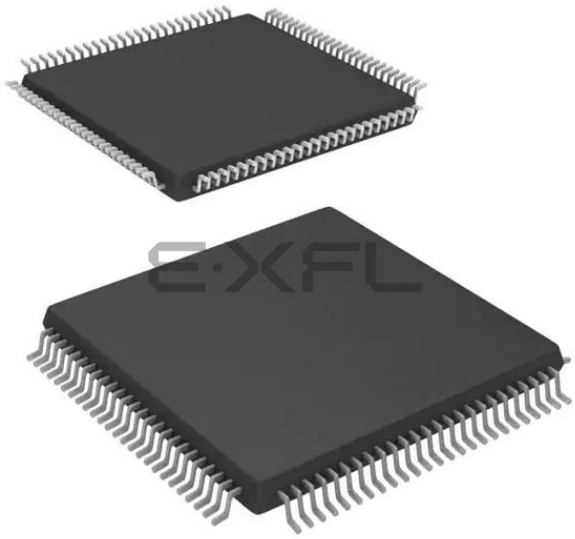

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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	36864
Number of I/O	68
Number of Gates	250000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 125°C (TA)
Package / Case	100-TQFP
Supplier Device Package	100-VQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/a3p250-1vqg100t

Automotive ProASIC3 Ordering Information

A3P1000 – 1 FG G 144 Y T

- **Part Number**
  - **Automotive ProASIC3 Devices**
    - A3P060 = 60,000 System Gates
    - A3P125 = 125,000 System Gates
    - A3P250 = 250,000 System Gates
    - A3P1000 = 1,000,000 System Gates
- **Speed Grade**
  - Blank = Standard
  - 1 = 15% Faster than Standard
- **Package Type**
  - VQ = Very Thin Quad Flat Pack (0.5 mm pitch)
  - FG = Fine Pitch Ball Grid Array (1.0 mm pitch)
  - QN = Quad Flat Pack (0.5 mm pitch)
- **Lead-Free Packaging**
  - Blank = Standard Packaging
  - G = RoHS-Compliant (Green) Packaging
- **Package Lead Count**
- **Security Feature**
  - Y = Device Includes License to Implement IP Based on the Cryptography Research, Inc. (CRI) Patent Portfolio
  - Blank = Device Does Not Include License to Implement IP Based on the Cryptography Research, Inc. (CRI) Patent Portfolio

LICENSED DPA COUNTERMEASURES

- **Application (Temperature Range)**
  - T = Grade 2 and Grade 1 AEC-Q100
    Grade 2 = 105°C T_A and 115°C T_J[1]
    Grade 1 = 125°C T_A and 135°C T_J[1]

Notes:

1. *T_A = Ambient temperature and T_J = Junction temperature.*
2. *Minimum order quantities apply. Contact your local Microsemi SoC Products Group sales office for details.*

Table 2-39 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew
Automotive-Case Conditions: T_J = 115°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V
Applicable to Advanced I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
4 mA	STD	0.63	8.28	0.05	1.10	0.45	8.44	7.13	1.42	1.37	10.85	9.55	ns
	-1	0.53	7.05	0.04	0.94	0.38	7.18	6.06	1.42	1.37	9.23	8.12	ns
6 mA	STD	0.63	5.31	0.05	1.10	0.45	5.41	4.40	1.60	1.68	7.83	6.82	ns
	-1	0.53	4.52	0.04	0.94	0.38	4.60	3.74	1.60	1.68	6.66	5.80	ns
8 mA	STD	0.63	5.31	0.05	1.10	0.45	5.41	4.40	1.60	1.68	7.83	6.82	ns
	-1	0.53	4.52	0.04	0.94	0.38	4.60	3.74	1.60	1.68	6.66	5.80	ns
12 mA	STD	0.63	3.82	0.05	1.10	0.45	3.89	1.51	3.47	1.88	6.31	2.70	ns
	-1	0.53	3.25	0.04	0.94	0.38	3.31	1.51	2.96	1.88	5.37	2.71	ns
16 mA	STD	0.63	3.60	0.05	1.10	0.45	1.78	1.37	3.53	3.98	2.95	2.57	ns
	-1	0.53	3.07	0.04	0.94	0.38	1.78	1.37	3.00	3.38	2.95	2.57	ns
24 mA	STD	0.63	3.33	0.05	1.10	0.45	1.64	1.13	3.60	4.39	2.81	2.33	ns
	-1	0.53	2.83	0.04	0.94	0.38	1.64	1.13	3.06	3.74	2.82	2.33	ns

Notes:

1. *Software default selection highlighted in gray.*
2. *For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.*

Table 2-40 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew
Automotive-Case Conditions: T_J = 115°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V
Applicable to Advanced I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
4 mA	STD	0.63	11.09	0.05	1.10	0.45	11.30	9.63	1.41	1.29	13.72	12.04	ns
	-1	0.53	9.44	0.04	0.94	0.38	9.61	8.19	1.41	1.29	11.67	10.25	ns
6 mA	STD	0.63	7.87	0.05	1.10	0.45	8.02	6.80	1.59	1.59	10.43	9.22	ns
	-1	0.53	6.69	0.04	0.94	0.38	6.82	5.78	1.59	1.60	8.88	7.84	ns
8 mA	STD	0.63	7.87	0.05	1.10	0.45	8.02	6.80	1.59	1.59	10.43	9.22	ns
	-1	0.53	6.69	0.04	0.94	0.38	6.82	5.78	1.59	1.60	8.88	7.84	ns
12 mA	STD	0.63	6.04	0.05	1.10	0.45	6.15	5.27	1.71	1.79	8.57	7.69	ns
	-1	0.53	5.14	0.04	0.94	0.38	5.23	4.48	1.71	1.79	7.29	6.54	ns
16 mA	STD	0.63	5.63	0.05	1.10	0.45	5.74	4.94	1.74	1.84	8.16	7.36	ns
	-1	0.53	4.79	0.04	0.94	0.38	4.88	4.20	1.74	1.84	6.94	6.26	ns
24 mA	STD	0.63	5.25	0.05	1.10	0.45	5.34	4.92	1.77	2.04	7.76	7.34	ns
	-1	0.53	4.46	0.04	0.94	0.38	4.55	4.18	1.77	2.04	6.60	6.24	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.

Table 2-48 • 2.5 V LVCMOS High Slew
Automotive-Case Conditions: T_J = 135°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V
Applicable to Standard Plus I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	STD	0.64	9.26	0.05	1.45	0.46	8.28	9.26	1.24	1.12	10.78	11.756	ns
	-1	0.55	7.87	0.04	1.23	0.39	7.05	7.87	1.24	1.13	9.17	10	ns
6 mA	STD	0.64	5.43	0.05	1.45	0.46	5.19	5.43	1.43	1.47	7.69	7.926	ns
	-1	0.55	4.62	0.04	1.23	0.39	4.42	4.62	1.43	1.47	6.55	6.743	ns
12 mA	STD	0.64	3.59	0.05	1.45	0.46	3.65	3.51	1.56	1.69	6.15	6.012	ns
	-1	0.55	3.05	0.04	1.23	0.39	3.11	2.99	1.56	1.69	5.23	5.114	ns

Notes:

1. *Software default selection highlighted in gray.*
2. *For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.*

Table 2-49 • 2.5 V LVCMOS Low Slew
Automotive-Case Conditions: T_J = 135°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V
Applicable to Standard Plus I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	STD	0.64	12.12	0.05	1.45	0.46	11.89	12.12	1.25	1.08	14.39	14.622	ns
	-1	0.55	10.31	0.04	1.23	0.39	10.12	10.31	1.25	1.08	12.24	12.438	ns
6 mA	STD	0.64	8.24	0.05	1.45	0.46	8.39	8.23	1.43	1.42	10.89	10.73	ns
	-1	0.55	7.01	0.04	1.23	0.39	7.14	7.00	1.43	1.42	9.26	9.128	ns
12 mA	STD	0.64	6.30	0.05	1.45	0.46	6.41	6.16	1.56	1.63	8.91	8.656	ns
	-1	0.55	5.35	0.04	1.23	0.39	5.45	5.24	1.56	1.63	7.58	7.364	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.

Table 2-50 • 2.5 V LVCMOS High Slew
Automotive-Case Conditions: T_J = 115°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V
Applicable to Advanced I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	STD	0.63	9.37	0.05	1.40	0.45	8.47	9.37	1.43	1.21	10.89	11.79	ns
	-1	0.53	7.97	0.04	1.19	0.38	7.21	7.97	1.43	1.21	9.27	10.03	ns
6 mA	STD	0.63	5.59	0.05	1.40	0.45	5.45	5.59	1.63	1.57	7.87	8.01	ns
	-1	0.53	4.75	0.04	1.19	0.38	4.63	4.75	1.63	1.57	6.69	6.81	ns
12 mA	STD	0.63	3.85	0.05	1.40	0.45	3.92	3.71	1.77	1.80	6.34	6.13	ns
	-1	0.53	3.28	0.04	1.19	0.38	3.34	3.16	1.77	1.80	5.39	5.22	ns
16 mA	STD	0.63	3.63	0.05	1.40	0.45	1.79	1.64	3.64	3.84	2.96	2.83	ns
	-1	0.53	3.08	0.04	1.19	0.38	1.79	1.64	3.09	3.27	2.96	2.83	ns
24 mA	STD	0.63	3.34	0.05	1.40	0.45	1.65	1.31	3.72	4.32	2.82	2.50	ns
	-1	0.53	2.84	0.04	1.19	0.38	1.65	1.31	3.16	3.68	2.82	2.50	ns

Notes:

1. *Software default selection highlighted in gray.*
2. *For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.*

Table 2-51 • 2.5 V LVCMOS Low Slew
Automotive-Case Conditions: TJ = 115°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V
Applicable to Advanced I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	STD	0.63	11.73	0.05	1.40	0.45	12.14	12.33	1.43	1.16	14.55	14.75	ns
	-1	0.53	9.98	0.04	1.19	0.38	10.32	10.49	1.43	1.16	12.38	12.55	ns
6 mA	STD	0.63	7.97	0.05	1.40	0.45	8.77	8.45	1.63	1.51	11.19	10.87	ns
	-1	0.53	6.78	0.04	1.19	0.38	7.46	7.19	1.63	1.52	9.52	9.25	ns
12 mA	STD	0.63	6.68	0.05	1.40	0.45	6.81	6.40	1.77	1.74	9.23	8.82	ns
	-1	0.53	5.69	0.04	1.19	0.38	5.79	5.45	1.77	1.74	7.85	7.50	ns
16 mA	STD	0.63	6.24	0.05	1.40	0.45	6.35	5.98	1.80	1.80	8.77	8.40	ns
	-1	0.53	5.30	0.04	1.19	0.38	5.40	5.08	1.80	1.80	7.46	7.14	ns
24 mA	STD	0.63	5.96	0.05	1.40	0.45	5.95	5.96	1.84	2.03	8.37	8.38	ns
	-1	0.53	5.07	0.04	1.19	0.38	5.06	5.07	1.84	2.03	7.12	7.12	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.

Table 2-58 • 1.8 V LVCMOS Low Slew
Automotive-Case Conditions: T_J = 135°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V
Applicable to Advanced I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	STD	0.64	17.36	0.05	1.45	0.46	15.78	17.36	1.53	0.87	18.28	19.864	ns
	-1	0.55	14.77	0.04	1.23	0.39	13.42	14.77	1.54	0.87	15.55	16.897	ns
4 mA	STD	0.64	11.71	0.05	1.45	0.46	11.64	11.71	1.78	1.48	14.14	14.214	ns
	-1	0.55	9.96	0.04	1.23	0.39	9.90	9.96	1.78	1.48	12.03	12.091	ns
6 mA	STD	0.64	9.00	0.05	1.45	0.46	9.17	8.77	1.95	1.77	11.67	11.267	ns
	-1	0.55	7.66	0.04	1.23	0.39	7.80	7.46	1.95	1.77	9.92	9.585	ns
8 mA	STD	0.64	8.39	0.05	1.45	0.46	8.54	8.16	1.99	1.85	11.04	10.66	ns
	-1	0.55	7.14	0.04	1.23	0.39	7.27	6.94	1.99	1.85	9.40	9.068	ns
12 mA	STD	0.64	8.15	0.05	1.45	0.46	8.09	8.15	2.05	2.14	10.59	10.654	ns
	-1	0.55	6.94	0.04	1.23	0.39	6.88	6.94	2.05	2.14	9.01	9.063	ns
16 mA	STD	0.64	8.15	0.05	1.45	0.46	8.09	8.15	2.05	2.14	10.59	10.654	ns
	-1	0.55	6.94	0.04	1.23	0.39	6.88	6.94	2.05	2.14	9.01	9.063	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.

Table 2-59 • 1.8 V LVCMOS High Slew
Automotive-Case Conditions: T_J = 135°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V
Applicable to Standard Plus I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	STD	0.64	13.26	0.05	1.36	0.46	9.75	12.67	1.24	0.82	12.26	15.17	ns
	-1	0.55	11.28	0.04	1.16	0.39	8.30	10.78	1.24	0.83	10.43	12.905	ns
4 mA	STD	0.64	7.73	0.05	1.36	0.46	6.13	7.25	1.46	1.41	8.63	9.749	ns
	-1	0.55	6.58	0.04	1.16	0.39	5.21	6.17	1.46	1.41	7.34	8.293	ns
6 mA	STD	0.64	4.97	0.05	1.36	0.46	4.29	4.54	1.62	1.68	6.79	7.039	ns
	-1	0.55	4.23	0.04	1.16	0.39	3.65	3.86	1.62	1.68	5.78	5.987	ns
8 mA	STD	0.64	4.39	0.05	1.36	0.46	4.29	4.54	1.62	1.68	6.79	7.039	ns
	-1	0.55	3.73	0.04	1.16	0.39	3.65	3.86	1.62	1.68	5.78	5.987	ns

Notes:

1. *Software default selection highlighted in gray.*
2. *For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.*

Table 2-60 • 1.8 V LVCMOS Low Slew
Automotive-Case Conditions: T_J = 135°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V
Applicable to Standard Plus I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	STD	0.64	17.36	0.05	1.45	0.46	15.09	16.55	1.24	0.79	17.59	19.052	ns
	-1	0.55	14.77	0.04	1.23	0.39	12.84	14.08	1.24	0.79	14.96	16.207	ns
4 mA	STD	0.64	11.71	0.05	1.45	0.46	10.88	11.07	1.47	1.35	13.38	13.567	ns
	-1	0.55	9.96	0.04	1.23	0.39	9.26	9.41	1.47	1.35	11.38	11.541	ns
6 mA	STD	0.64	9.00	0.05	1.45	0.46	8.47	8.18	1.62	1.62	10.97	10.685	ns
	-1	0.55	7.66	0.04	1.23	0.39	7.21	6.96	1.62	1.62	9.33	9.089	ns
8 mA	STD	0.64	8.39	0.05	1.45	0.46	8.47	8.18	1.62	1.62	10.97	10.685	ns
	-1	0.55	7.14	0.04	1.23	0.39	7.21	6.96	1.62	1.62	9.33	9.089	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.

Table 2-61 • 1.8 V LVCMOS High Slew
Automotive-Case Conditions: T_J = 115°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V
Applicable to Advanced I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	STD	0.63	12.83	0.05	1.32	0.45	9.88	12.83	1.48	0.87	12.30	15.25	ns
	-1	0.53	10.92	0.04	1.12	0.38	8.41	10.92	1.48	0.87	10.46	12.97	ns
4 mA	STD	0.63	7.48	0.05	1.32	0.45	6.34	7.48	1.72	1.49	8.76	9.90	ns
	-1	0.53	6.36	0.04	1.12	0.38	5.39	6.36	1.72	1.49	7.45	8.42	ns
6 mA	STD	0.63	4.81	0.05	1.32	0.45	4.52	4.81	1.89	1.77	6.94	7.23	ns
	-1	0.53	4.09	0.04	1.12	0.38	3.85	4.09	1.89	1.77	5.90	6.15	ns
8 mA	STD	0.63	4.25	0.05	1.32	0.45	4.25	4.25	1.92	1.85	6.67	6.66	ns
	-1	0.53	3.61	0.04	1.12	0.38	3.61	3.61	1.93	1.85	5.67	5.67	ns
12 mA	STD	0.63	3.82	0.05	1.32	0.45	1.89	1.63	4.00	4.41	3.06	2.82	ns
	-1	0.53	3.25	0.04	1.12	0.38	1.89	1.63	3.41	3.75	3.06	2.82	ns
16 mA	STD	0.63	3.82	0.05	1.32	0.45	1.89	1.63	4.00	4.41	3.06	2.82	ns
	-1	0.53	3.25	0.04	1.12	0.38	1.89	1.63	3.41	3.75	3.06	2.82	ns

Notes:

1. *Software default selection highlighted in gray.*
2. *For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.*

Fully Registered I/O Buffers with Synchronous Enable and Asynchronous Clear

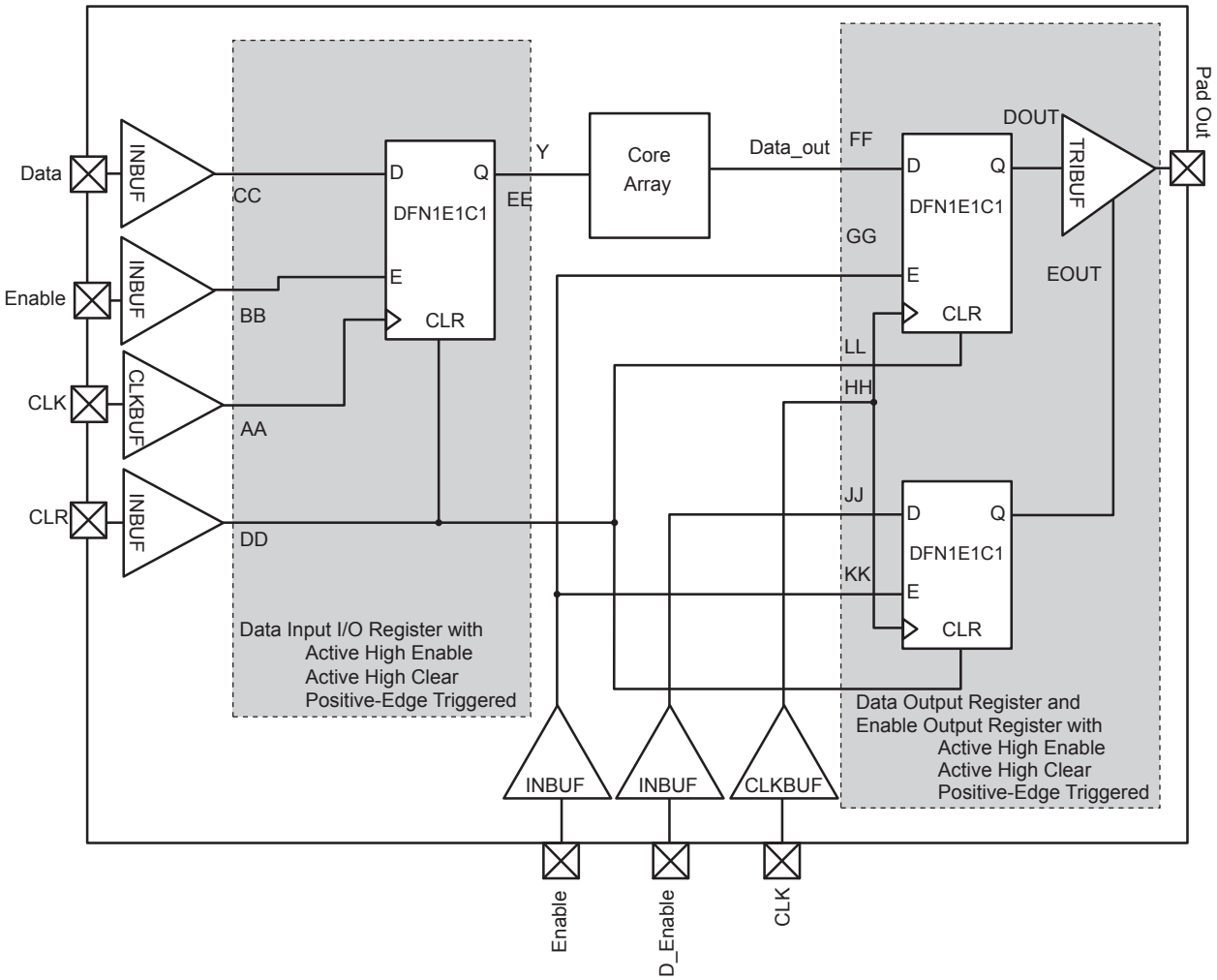


Figure 2-16 • **Timing Model of the Registered I/O Buffers with Synchronous Enable and Asynchronous Clear**

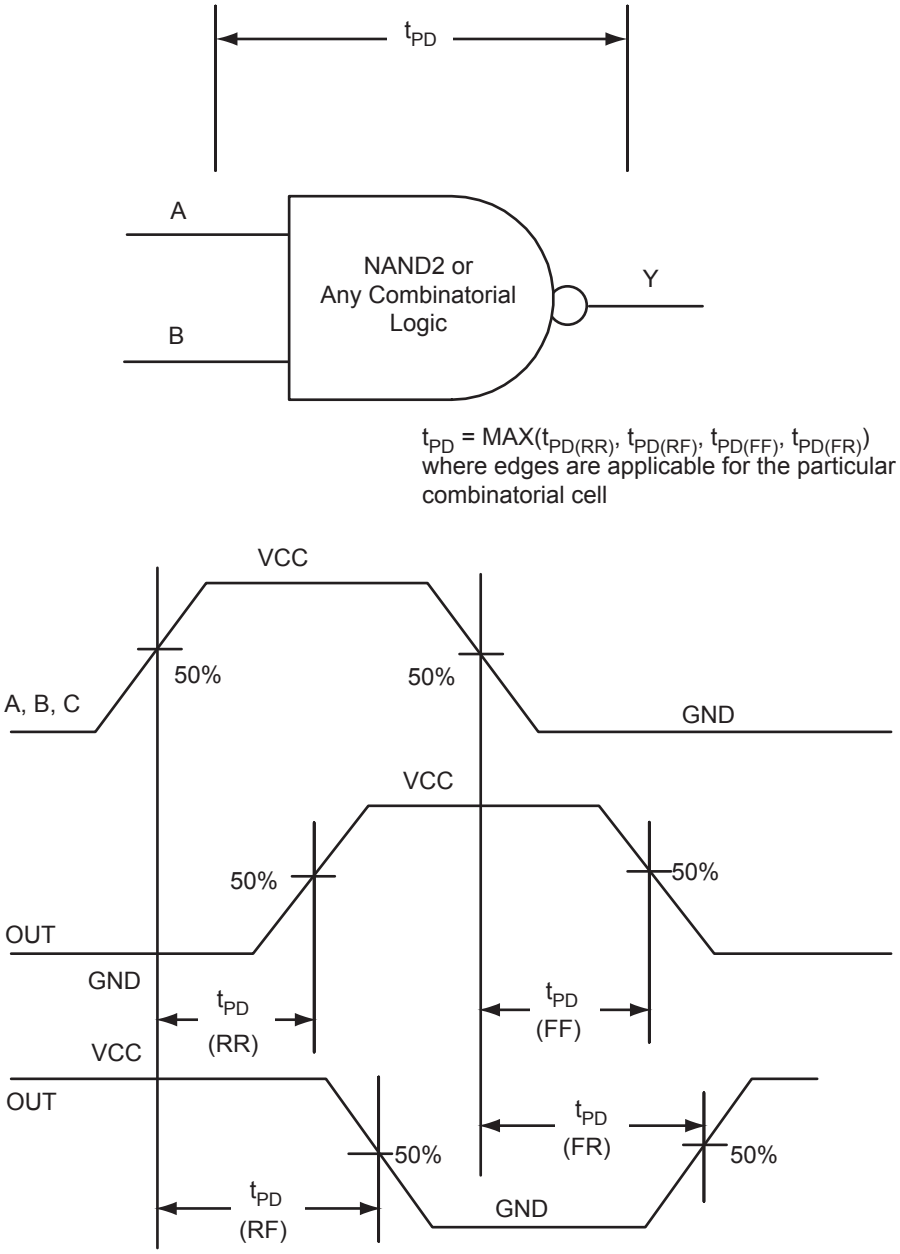


Figure 2-25 • **Timing Model and Waveforms**

Global Tree Timing Characteristics

Global clock delays include the central rib delay, the spine delay, and the row delay. Delays do not include I/O input buffer clock delays, as these are I/O standard–dependent, and the clock may be driven and conditioned internally by the CCC module. For more details on clock conditioning capabilities, refer to the "Clock Conditioning Circuits" section on page 2-80. Table 2-114 on page 2-79 to Table 2-125 on page 2-97 present minimum and maximum global clock delays within each device. Minimum and maximum delays are measured with minimum and maximum loading.

Timing Characteristics

Table 2-108 • A3P060 Global Resource
Commercial-Case Conditions: T_J = 135°C, VCC = 1.425 V

Parameter	Description	–1		Std.		Units
		Min.[1]	Max.[2]	Min.[1]	Max.[2]	
t_{RCKL}	Input Low Delay for Global Clock	0.87	1.16	1.02	1.37	ns
t_{RCKH}	Input High Delay for Global Clock	0.86	1.20	1.01	1.42	ns
$t_{RCKMPWH}$	Minimum Pulse Width High for Global Clock	0.80		0.94		ns
$t_{RCKMPWL}$	Minimum Pulse Width Low for Global Clock	0.98		1.15		ns
t_{RCKSW}	Maximum Skew for Global Clock		0.35		0.41	ns

Notes:

1. *Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).*
2. *Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).*
3. *For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.*

Table 2-109 • A3P060 Global Resource
Commercial-Case Conditions: T_J = 115°C, VCC = 1.425 V

Parameter	Description	–1		Std.		Units
		Min.[1]	Max.[2]	Min.[1]	Max.[2]	
t_{RCKL}	Input Low Delay for Global Clock	0.85	1.13	1.00	1.33	ns
t_{RCKH}	Input High Delay for Global Clock	0.84	1.18	0.99	1.38	ns
$t_{RCKMPWH}$	Minimum Pulse Width High for Global Clock	0.80		0.94		ns
$t_{RCKMPWL}$	Minimum Pulse Width Low for Global Clock	0.98		1.15		ns
t_{RCKSW}	Maximum Skew for Global Clock		0.34		0.40	ns

Notes:

1. *Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).*
2. *Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).*
3. *For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.*

Table 2-110 • A3P125 Global Resource
Commercial-Case Conditions: T_J = 135°C, VCC = 1.425 V

Parameter	Description	–1		Std.		Units
		Min.[1]	Max.[2]	Min.[1]	Max.[2]	
t_{RCKL}	Input Low Delay for Global Clock	0.93	1.22	1.09	1.43	ns
t_{RCKH}	Input High Delay for Global Clock	0.92	1.26	1.08	1.49	ns
$t_{RCKMPWH}$	Minimum Pulse Width High for Global Clock	0.80		0.94		ns
$t_{RCKMPWL}$	Minimum Pulse Width Low for Global Clock	0.98		1.15		ns
t_{RCKSW}	Maximum Skew for Global Clock		0.35		0.41	ns

Notes:

1. *Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).*
2. *Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).*
3. *For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.*

Table 2-111 • A3P125 Global Resource
Commercial-Case Conditions: T_J = 115°C, VCC = 1.425 V

Parameter	Description	–1		Std.		Units
		Min.[1]	Max.[2]	Min.[1]	Max.[2]	
t_{RCKL}	Input Low Delay for Global Clock	0.90	1.19	1.06	1.40	ns
t_{RCKH}	Input High Delay for Global Clock	0.90	1.23	1.05	1.45	ns
$t_{RCKMPWH}$	Minimum Pulse Width High for Global Clock	0.80		0.94		ns
$t_{RCKMPWL}$	Minimum Pulse Width Low for Global Clock	0.98		1.15		ns
t_{RCKSW}	Maximum Skew for Global Clock		0.34		0.40	ns

Notes:

1. *Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).*
2. *Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).*
3. *For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.*

Table 2-112 • A3P250 Global Resource
Commercial-Case Conditions: T_J = 135°C, VCC = 1.425 V

Parameter	Description	–1		Std.		Units
		Min.[1]	Max.[2]	Min.[1]	Max.[2]	
t_{RCKL}	Input Low Delay for Global Clock	0.96	1.25	1.13	1.47	ns
t_{RCKH}	Input High Delay for Global Clock	0.94	1.28	1.10	1.51	ns
$t_{RCKMPWH}$	Minimum Pulse Width High for Global Clock	0.80		0.94		ns
$t_{RCKMPWL}$	Minimum Pulse Width Low for Global Clock	0.98		1.15		ns
t_{RCKSW}	Maximum Skew for Global Clock		0.35		0.41	ns

Notes:

1. *Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).*
2. *Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).*
3. *For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.*

Table 2-113 • A3P250 Global Resource
Commercial-Case Conditions: T_J = 115°C, VCC = 1.425 V

Parameter	Description	–1		Std.		Units
		Min.[1]	Max.[2]	Min.[1]	Max.[2]	
t_{RCKL}	Input Low Delay for Global Clock	0.94	1.22	1.10	1.44	ns
t_{RCKH}	Input High Delay for Global Clock	0.92	1.25	1.08	1.47	ns
$t_{RCKMPWH}$	Minimum Pulse Width High for Global Clock	0.80		0.94		ns
$t_{RCKMPWL}$	Minimum Pulse Width Low for Global Clock	0.98		1.15		ns
t_{RCKSW}	Maximum Skew for Global Clock		0.34		0.40	ns

Notes:

1. *Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).*
2. *Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).*
3. *For specific junction temperature and voltage supply levels, refer to Table 2-5 on page 2-5 for derating values.*

Timing Waveforms

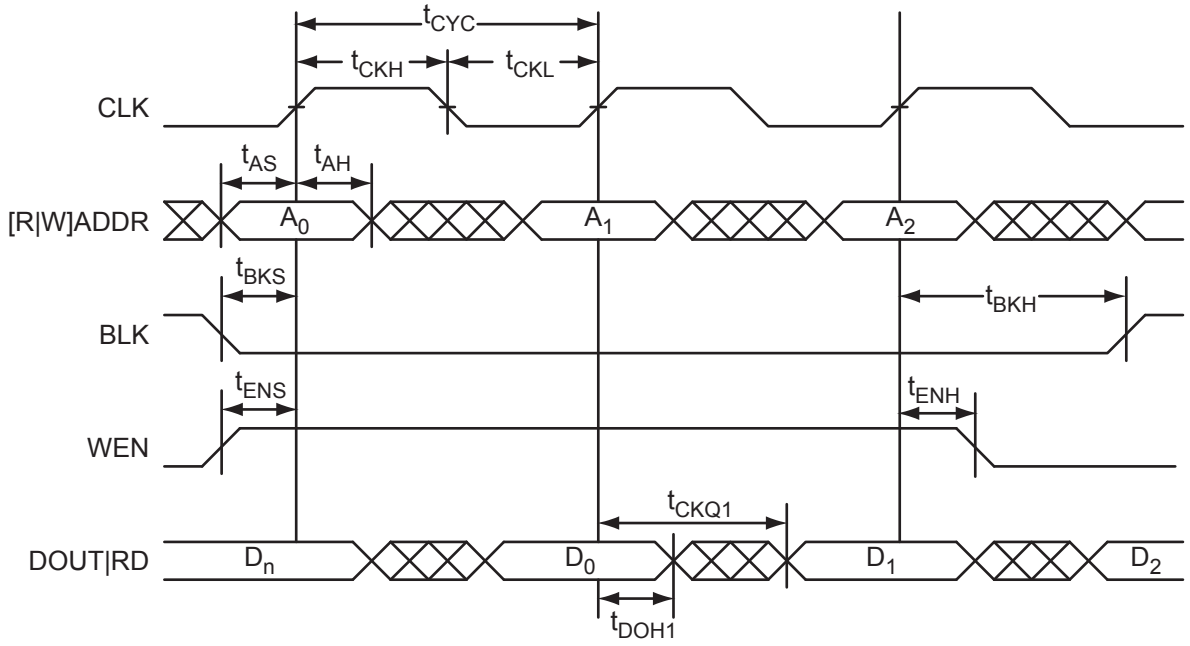


Figure 2-31 • **RAM Read for Pass-Through Output. Applicable to Both RAM4K9 and RAM512x18.**

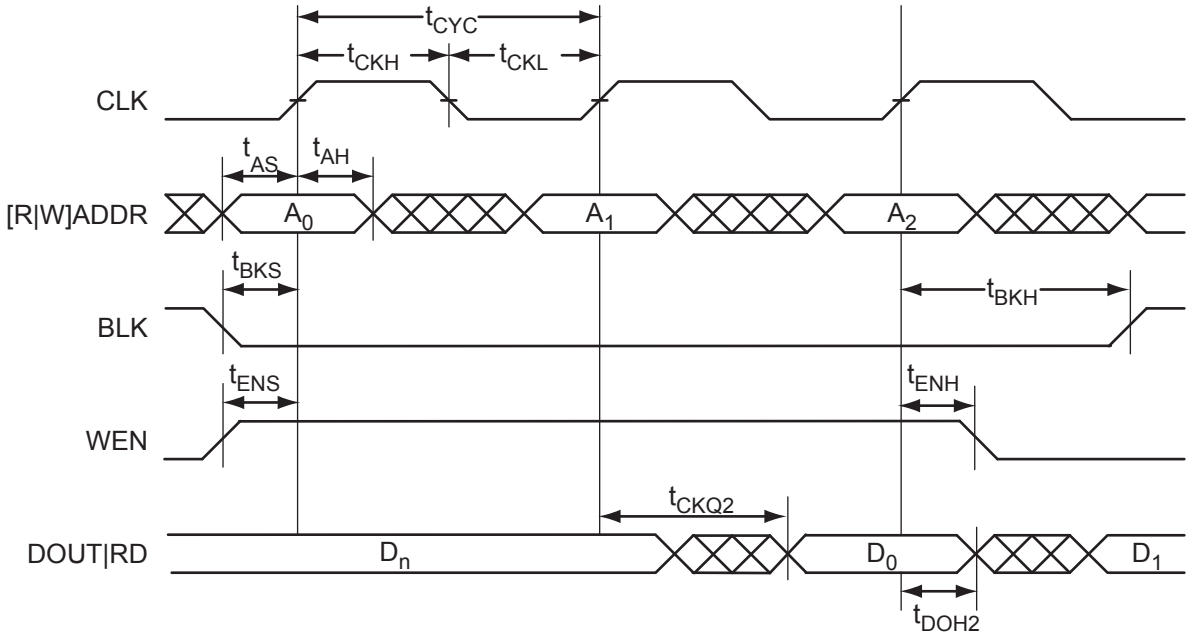


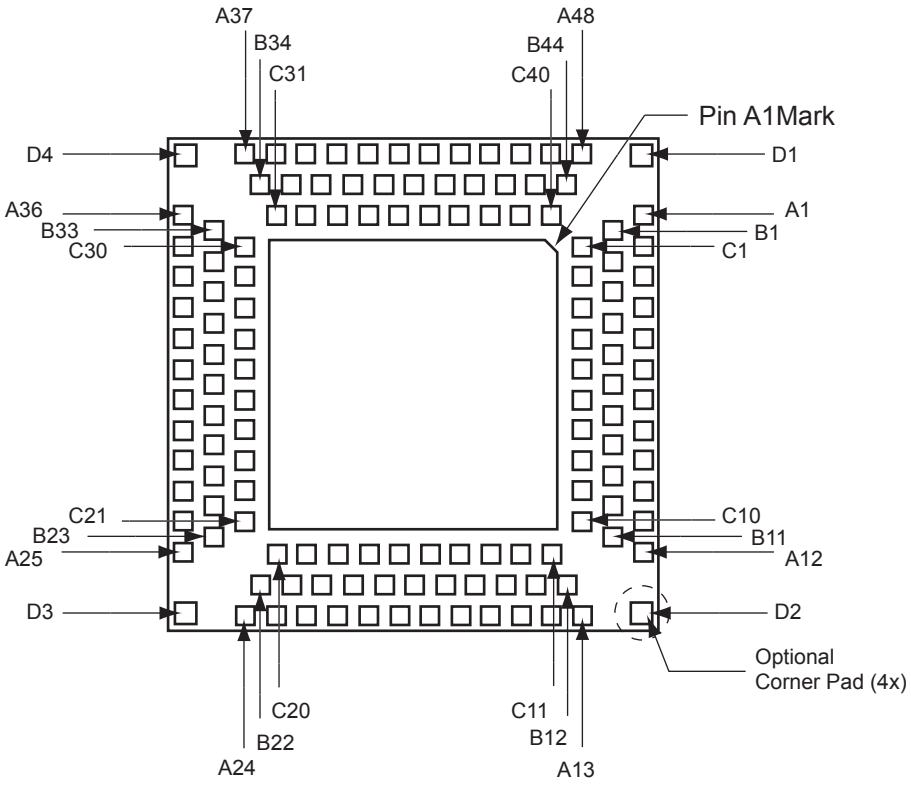
Figure 2-32 • **RAM Read for Pipelined Output. Applicable to Both RAM4K9 and RAM512x18.**

VQ100	
Pin Number	A3P250 Function
1	GND
2	GAA2/IO118UDB3
3	IO118VDB3
4	GAB2/IO117UDB3
5	IO117VDB3
6	GAC2/IO116UDB3
7	IO116VDB3
8	IO112PSB3
9	GND
10	GFB1/IO109PDB3
11	GFB0/IO109NDB3
12	VCOMPLF
13	GFA0/IO108NPB3
14	VCCPLF
15	GFA1/IO108PPB3
16	GFA2/IO107PSB3
17	VCC
18	VCCIB3
19	GFC2/IO105PSB3
20	GEC1/IO100PDB3
21	GEC0/IO100NDB3
22	GEA1/IO98PDB3
23	GEA0/IO98NDB3
24	VMV3
25	GNDQ
26	GEA2/IO97RSB2
27	GEB2/IO96RSB2
28	GEC2/IO95RSB2
29	IO93RSB2
30	IO92RSB2
31	IO91RSB2
32	IO90RSB2
33	IO88RSB2
34	IO86RSB2

VQ100	
Pin Number	A3P250 Function
35	IO85RSB2
36	IO84RSB2
37	VCC
38	GND
39	VCCIB2
40	IO77RSB2
41	IO74RSB2
42	IO71RSB2
43	GDC2/IO63RSB2
44	GDB2/IO62RSB2
45	GDA2/IO61RSB2
46	GNDQ
47	TCK
48	TDI
49	TMS
50	VMV2
51	GND
52	VPUMP
53	NC
54	TDO
55	TRST
56	VJTAG
57	GDA1/IO60USB1
58	GDC0/IO58VDB1
59	GDC1/IO58UDB1
60	IO52NDB1
61	GCB2/IO52PDB1
62	GCA1/IO50PDB1
63	GCA0/IO50NDB1
64	GCC0/IO48NDB1
65	GCC1/IO48PDB1
66	VCCIB1
67	GND
68	VCC

VQ100	
Pin Number	A3P250 Function
69	IO43NDB1
70	GBC2/IO43PDB1
71	GBB2/IO42PSB1
72	IO41NDB1
73	GBA2/IO41PDB1
74	VMV1
75	GNDQ
76	GBA1/IO40RSB0
77	GBA0/IO39RSB0
78	GBB1/IO38RSB0
79	GBB0/IO37RSB0
80	GBC1/IO36RSB0
81	GBC0/IO35RSB0
82	IO29RSB0
83	IO27RSB0
84	IO25RSB0
85	IO23RSB0
86	IO21RSB0
87	VCCIB0
88	GND
89	VCC
90	IO15RSB0
91	IO13RSB0
92	IO11RSB0
93	GAC1/IO05RSB0
94	GAC0/IO04RSB0
95	GAB1/IO03RSB0
96	GAB0/IO02RSB0
97	GAA1/IO01RSB0
98	GAA0/IO00RSB0
99	GNDQ
100	VMV0

QN132



Notes:

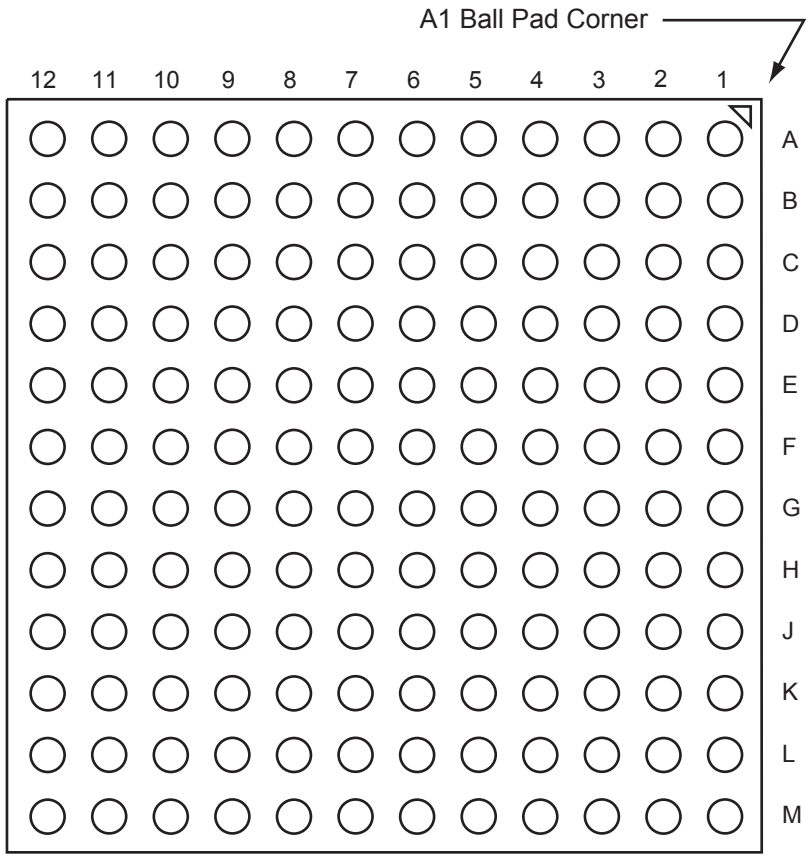
1. *This is the bottom view of the package.*
2. *The die attach paddle center of the package is tied to ground (GND).*

Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.actel.com/products/solutions/package/docs.aspx.

QN132	
Pin Number	A3P125 Function
C17	IO83RSB1
C18	VCCIB1
C19	TCK
C20	VMV1
C21	VPUMP
C22	VJTAG
C23	VCCIB0
C24	NC
C25	NC
C26	GCA1/IO55RSB0
C27	GCC0/IO52RSB0
C28	VCCIB0
C29	IO42RSB0
C30	GNDQ
C31	GBA1/IO40RSB0
C32	GBB0/IO37RSB0
C33	VCC
C34	IO24RSB0
C35	IO19RSB0
C36	IO16RSB0
C37	IO10RSB0
C38	VCCIB0
C39	GAB1/IO03RSB0
C40	VMV0
D1	GND
D2	GND
D3	GND
D4	GND

FG144



Note: This is the bottom view of the package.

Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.actel.com/products/solutions/package/docs.aspx.

FG144	
Pin Number	A3P060 Function
K1	GEB0/IO74RSB1
K2	GEA1/IO73RSB1
K3	GEA0/IO72RSB1
K4	GEA2/IO71RSB1
K5	IO65RSB1
K6	IO64RSB1
K7	GND
K8	IO57RSB1
K9	GDC2/IO56RSB1
K10	GND
K11	GDA0/IO50RSB0
K12	GDB0/IO48RSB0
L1	GND
L2	VMV1
L3	GEB2/IO70RSB1
L4	IO67RSB1
L5	VCCIB1
L6	IO62RSB1
L7	IO59RSB1
L8	IO58RSB1
L9	TMS
L10	VJTAG
L11	VMV1
L12	TRST
M1	GNDQ
M2	GEC2/IO69RSB1
M3	IO68RSB1
M4	IO66RSB1
M5	IO63RSB1
M6	IO61RSB1
M7	IO60RSB1
M8	NC
M9	TDI
M10	VCCIB1
M11	VPUMP
M12	GNDQ

FG144	
Pin Number	A3P250 Function
K1	GEB0/IO99NDB3
K2	GEA1/IO98PDB3
K3	GEA0/IO98NDB3
K4	GEA2/IO97RSB2
K5	IO90RSB2
K6	IO84RSB2
K7	GND
K8	IO66RSB2
K9	GDC2/IO63RSB2
K10	GND
K11	GDA0/IO60VDB1
K12	GDB0/IO59VDB1
L1	GND
L2	VMV3
L3	GEB2/IO96RSB2
L4	IO91RSB2
L5	VCCIB2
L6	IO82RSB2
L7	IO80RSB2
L8	IO72RSB2
L9	TMS
L10	VJTAG
L11	VMV2
L12	TRST
M1	GNDQ
M2	GEC2/IO95RSB2
M3	IO92RSB2
M4	IO89RSB2
M5	IO87RSB2
M6	IO85RSB2
M7	IO78RSB2
M8	IO76RSB2
M9	TDI
M10	VCCIB2
M11	VPUMP
M12	GNDQ

FG144	
Pin Number	A3P1000 Function
A1	GNDQ
A2	VMV0
A3	GAB0/IO02RSB0
A4	GAB1/IO03RSB0
A5	IO10RSB0
A6	GND
A7	IO44RSB0
A8	VCC
A9	IO69RSB0
A10	GBA0/IO76RSB0
A11	GBA1/IO77RSB0
A12	GNDQ
B1	GAB2/IO224PDB3
B2	GND
B3	GAA0/IO00RSB0
B4	GAA1/IO01RSB0
B5	IO13RSB0
B6	IO26RSB0
B7	IO35RSB0
B8	IO60RSB0
B9	GBB0/IO74RSB0
B10	GBB1/IO75RSB0
B11	GND
B12	VMV1
C1	IO224NDB3
C2	GFA2/IO206PPB3
C3	GAC2/IO223PDB3
C4	VCC
C5	IO16RSB0
C6	IO29RSB0
C7	IO32RSB0
C8	IO63RSB0
C9	IO66RSB0
C10	GBA2/IO78PDB1
C11	IO78NDB1
C12	GBC2/IO80PPB1

FG144	
Pin Number	A3P1000 Function
D1	IO213PDB3
D2	IO213NDB3
D3	IO223NDB3
D4	GAA2/IO225PPB3
D5	GAC0/IO04RSB0
D6	GAC1/IO05RSB0
D7	GBC0/IO72RSB0
D8	GBC1/IO73RSB0
D9	GBB2/IO79PDB1
D10	IO79NDB1
D11	IO80NPB1
D12	GCB1/IO92PPB1
E1	VCC
E2	GFC0/IO209NDB3
E3	GFC1/IO209PDB3
E4	VCCIB3
E5	IO225NPB3
E6	VCCIB0
E7	VCCIB0
E8	GCC1/IO91PDB1
E9	VCCIB1
E10	VCC
E11	GCA0/IO93NDB1
E12	IO94NDB1
F1	GFB0/IO208NPB3
F2	VCOMPLF
F3	GFB1/IO208PPB3
F4	IO206NPB3
F5	GND
F6	GND
F7	GND
F8	GCC0/IO91NDB1
F9	GCB0/IO92NPB1
F10	GND
F11	GCA1/IO93PDB1
F12	GCA2/IO94PDB1

FG144	
Pin Number	A3P1000 Function
G1	GFA1/IO207PPB3
G2	GND
G3	VCCPLF
G4	GFA0/IO207NPB3
G5	GND
G6	GND
G7	GND
G8	GDC1/IO111PPB1
G9	IO96NDB1
G10	GCC2/IO96PDB1
G11	IO95NDB1
G12	GCB2/IO95PDB1
H1	VCC
H2	GFB2/IO205PDB3
H3	GFC2/IO204PSB3
H4	GEC1/IO190PDB3
H5	VCC
H6	IO105PDB1
H7	IO105NDB1
H8	GDB2/IO115RSB2
H9	GDC0/IO111NPB1
H10	VCCIB1
H11	IO101PSB1
H12	VCC
J1	GEB1/IO189PDB3
J2	IO205NDB3
J3	VCCIB3
J4	GEC0/IO190NDB3
J5	IO160RSB2
J6	IO157RSB2
J7	VCC
J8	TCK
J9	GDA2/IO114RSB2
J10	TDO
J11	GDA1/IO113PDB1
J12	GDB1/IO112PDB1